74HC366; 74HCT366

Hex buffer/line driver; 3-state; inverting
Rev. 5 — 2 February 2016

Product data sheet

1. General description

The 74HC366; 74HCT366 is a hex inverting buffer/line driver with 3-state outputs controlled by the output enable inputs (OEn). A HIGH on OEn causes the outputs to assume a high impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Inverting outputs
- Input levels:
 - ◆ For 74HC366: CMOS level
 - For 74HC366: TTL level
- Complies with JEDEC standard no. 7A
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from −40 °C to +85 °C and from −40 °C to +125 °C
- Multiple package options

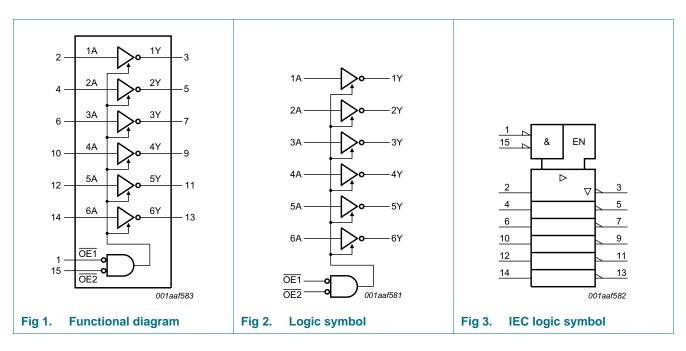
Ordering information

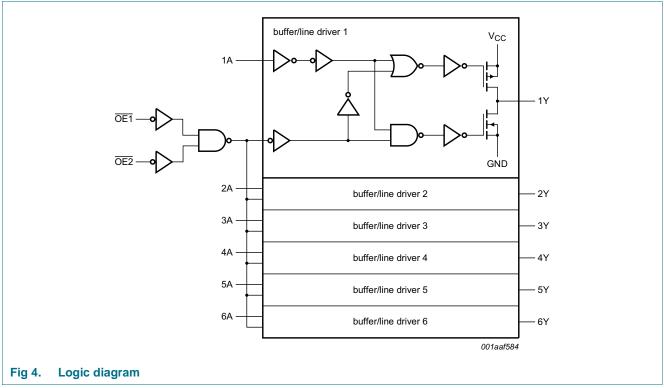
Table 1. **Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
74HC366				
74HC366D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC366PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HCT366				
74HCT366D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT366DB	−40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HCT366PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1



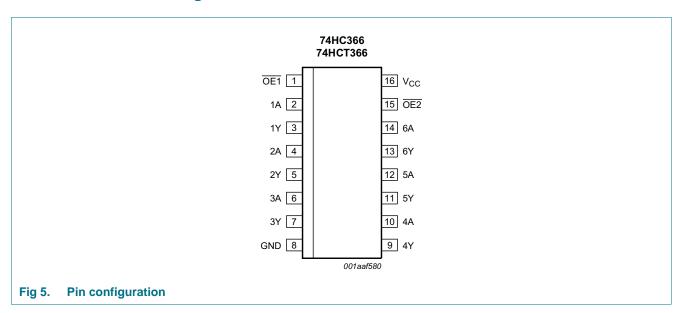
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
OE1, OE2	1, 15	output enable input (active LOW)
1A, 2A, 3A, 4A, 5A, 6A	2, 4, 6, 10, 12, 14	data input
1Y, 2Y, 3Y, 4Y, 5Y, 6Y	3, 5, 7, 9, 11, 13	data output
GND	8	ground (0 V)
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table[1]

Control		Input	Output
OE1	OE2	nA	nY
L	L	L	Н
L	L	Н	L
X	Н	X	Z
Н	X	X	Z

- [1] H = HIGH voltage level;
 - L = LOW voltage level;
 - X = don't care;
 - Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±35	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-	-70	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	SO16 package [1]	-	500	mW
		SSOP16 package [2]	-	500	mW
		TSSOP16 package [2]	-	500	mW

^[1] For SO16 packages: P_{tot} derates linearly with 8 mW/K above 70 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC366			7	Unit		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

^[2] For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

9. Static characteristics

Table 6. Static characteristics 74HC366

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$T_{amb} = 2$	25 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	1.2 - 2.4 - 3.2 - 0.8 0.5 2.1 1.35 2.8 1.8 - 2.0 - 4.5 - 6.0 - 4.32 - 5.81 - 0 0.1 0 0.1 0 0.1 0 0.1 0 0.15 0.26 - ±0.1 - ±0.5 - 8.0 3.5	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	- 0.5 1.35 1.8 	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}	-	-	-	
		$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	2	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0		V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
/ _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.5	μΑ
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	μΑ
Cı	input capacitance		-	3.5	-	pF
T _{amb} = -	-40 °C to +85 °C		l .	1		
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
-	. 3	$I_{O} = -20 \mu\text{A}; V_{CC} = 2.0 \text{V}$	1.9	-	-	V
		$I_{O} = -20 \mu A$; $V_{CC} = 4.5 \text{ V}$	4.4	4.4 -	-	V
		$I_{O} = -20 \mu\text{A}; V_{CC} = 6.0 \text{V}$	5.9	-	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_0 = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	0.0 1			V

Table 6. Static characteristics 74HC366 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20 \mu A; V_{CC} = 2.0 \text{ V}$	-	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	-	- 0.1 - 0.33 - 0.33 - ±1.0 - ±5.0 - 80	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$;	-	-	±1.0	μΑ
I _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±5.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μΑ
T _{amb} = -	40 °C to +125 °C					
V_{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	V	
V_{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.1 0.33 0.33 ±1.0 ±5.0 80 - - - 0.5 1.35 1.8 - - - - - 0.1 0.1 0.4 0.4 ±1.0	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-		V	
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}			0.1 0.1 0.33 0.33 ±1.0 ±5.0 80 - - 0.5 1.35 1.8 - - - - 0.1 0.1 0.1 0.4 0.4 ±1.0 ±10.0	
		$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	-		V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	-		V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	-		V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20 \mu A; V_{CC} = 2.0 \text{ V}$	-	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ
I _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±10.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μΑ

Table 7. Static characteristics 74HCT366

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 ℃					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
	voltage	$I_{O} = -20 \mu A$	4.4	4.5	-	V
		$I_{O} = -6.0 \text{ mA}$	3.98	4.32	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	0	0 0.1 16 0.26 ±0.1 ±0.5 8.0 00 360 00 360 00 320	V
		I _O = 6.0 mA	-	0.16	0.26	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.5	μΑ
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	μΑ
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$				
		pins nA	-	100	360	μΑ
		pin OE1	-	100	360	μΑ
		pin OE2	-	90	320	μΑ
Cı	input capacitance		-	3.5	-	pF
T _{amb} = -	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
	voltage	$I_{O} = -20 \mu A$	4.4	-	-	V
		$I_{O} = -6.0 \text{ mA}$	3.84	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}$	-	-	0.33	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
loz	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$			±5.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μΑ
Δl _{CC}	additional supply current	$V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$				
		pins nA	-	-	450	μΑ
		pin OE1	-	-	450	μΑ
		pin OE2	-	-	400	μА

Table 7. Static characteristics 74HCT366 ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
	voltage	$I_{O} = -20 \mu A$	4.4	-	-	V
		$I_{O} = -6.0 \text{ mA}$	3.7	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
		$I_{O} = 20 \mu A$	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}$	-	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±10.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μΑ
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$				
		pins nA	-	-	490	μΑ
		pin OE1	-	-	490	μΑ
		pin OE2	-	-	441	μΑ

10. Dynamic characteristics

Table 8. Dynamic characteristics 74HC366

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 ℃						-1
t _{pd}	propagation delay	nA to nY; see Figure 6	[1]				
		V _{CC} = 2.0 V		-	33	100	ns
		V _{CC} = 4.5 V		-	12	100 20 - 17 150 30 26 150 30 26	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	10	-	ns
		V _{CC} = 6.0 V		-	10	17	ns
t _{en}	enable time	OEn to nY; see Figure 7	[2]				
		V _{CC} = 2.0 V		-	44	150	ns
		V _{CC} = 4.5 V		-	16	30	ns
		V _{CC} = 6.0 V		-	13	26	ns
t _{dis}	disable time	OEn to nY; see Figure 7	[3]				
		V _{CC} = 2.0 V		-	55	20 - 17 150 30 26 150 30 26	ns
		V _{CC} = 4.5 V		-	20	30	ns
		V _{CC} = 6.0 V		-	16	26	ns
t _t	transition time	see Figure 6	<u>[4]</u>				
	V _C r	V _{CC} = 2.0 V		-	14	60	ns
		V _{CC} = 4.5 V		-	5	12	ns
		V _{CC} = 6.0 V		-	4	10	ns

 Table 8.
 Dynamic characteristics 74HC366 ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
C _{PD}	power dissipation capacitance	per buffer; $V_I = GND$ to V_{CC}	[5]	-	30	-	pF
T _{amb} = -	40 °C to +85 °C						
t _{pd}	propagation delay	nA to nY; see Figure 6	[1]				
		V _{CC} = 2.0 V		-	-	125	ns
		V _{CC} = 4.5 V		-	-	25	ns
		V _{CC} = 6.0 V		-	-	125	ns
t _{en}	enable time	OEn to nY; see Figure 7	[2]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	125 25 21 190 38 33 190 38 33 75 15 13 26 225 45 38	ns
t _{dis}	disable time	OEn to nY; see Figure 7	[3]			125 25 21 190 38 33 190 38 33 75 15 13 150 30 26 225 45 38	
		V _{CC} = 2.0 V		-	-		ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	38 33 75 15	ns
t _t	transition time	see Figure 6	[4]				
		V _{CC} = 2.0 V		-	-	25 21 190 38 33 190 38 33 75 15 13 26 225 45 38	ns
		V _{CC} = 4.5 V		-	-	15	ns
		V _{CC} = 6.0 V		-	-	13	ns
$T_{amb} = -$	40 °C to +125 °C						
t _{pd}	propagation delay	nA to nY; see Figure 6	[1]			25 21 190 38 33 190 38 33 75 15 13 150 30 26 225 45 38	
		V _{CC} = 2.0 V		-	-	150	ns
		V _{CC} = 4.5 V		-	-	30	ns
		V _{CC} = 6.0 V		-	-	26	ns
t _{en}	enable time	OEn to nY; see Figure 7	[2]			25 21 190 38 33 190 38 33 75 15 13 150 30 26 225 45 38	
		V _{CC} = 2.0 V		-	-		ns
		V _{CC} = 4.5 V		-	-	45	ns
		V _{CC} = 6.0 V		-	-	38	ns
t _{dis}	disable time	OEn to nY; see Figure 7	[3]				
		V _{CC} = 2.0 V		-	-	225	ns
		V _{CC} = 4.5 V		-	-	38 33 75 15 13 150 30 26 225 45 38	ns
		V _{CC} = 6.0 V		-	-	38	ns

Table 8. Dynamic characteristics 74HC366 ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions	N	Viin	Тур	Max	Unit
t _t	transition time	see Figure 6	1				
		V _{CC} = 2.0 V		-	-	90	ns
		V _{CC} = 4.5 V		-	-	18	ns
		V _{CC} = 6.0 V		-	-	15	ns

- [1] t_{pd} is the same as t_{PHL} and t_{PLH}.
- [2] t_{en} is the same as t_{PZH} and t_{PZL} .
- [3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .
- [4] t_t is the same as t_{THL} and t_{TLH} .
- [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

Table 9. Dynamic characteristics 74HCT366

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 °C						
t _{pd} propagation delay		nA to nY; see Figure 6	[1]				
		V _{CC} = 4.5 V		-	13	24	ns
		V _{CC} = 5 V; C _L = 15 pF		-	11	-	ns
t _{en}	enable time	OEn to nY; V _{CC} = 4.5 V; see Figure 7	[2]	-	16	35	ns
t _{dis}	disable time	OEn to nY; V _{CC} = 4.5 V; see Figure 7		-	20	35	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Figure 6</u>	V _{CC} = 4.5 V; see <u>Figure 6</u> [4]		5	12	ns
C_{PD}	power dissipation capacitance	per buffer; $V_I = GND$ to $(V_{CC} - 1.5 V)$	[5]	-	30	-	pF
T _{amb} = -	40 °C to +85 °C				1		
t _{pd}	propagation delay	nA to nY; V _{CC} = 4.5 V; see Figure 6	[1]	-	-	30	ns
t _{en}	enable time	OEn to nY; V _{CC} = 4.5 V; see Figure 7	$\overline{\text{OEn}}$ to nY; $V_{CC} = 4.5 \text{ V}$; see Figure 7		-	44	ns
t _{dis}	disable time	OEn to nY; V _{CC} = 4.5 V; see Figure 7	[3]	-	-	44	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Figure 6</u>	[4]	-	-	15	ns

Table 9. Dynamic characteristics 74HCT366 ... continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$T_{amb} = -4$	40 °C to +125 °C		·				
t _{pd}	propagation delay	nA to nY; V _{CC} = 4.5 V; see Figure 6	<u>[1]</u>	-	-	36	ns
t _{en}	enable time	OEn to nY; V _{CC} = 4.5 V; see Figure 7	[2]	-	-	53	ns
t _{dis}	disable time	OEn to nY; V _{CC} = 4.5 V; see Figure 7	[3]	-	-	53	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Figure 6</u>	<u>[4]</u>	-	-	18	ns

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [2] t_{en} is the same as t_{PZH} and t_{PZL} .
- [3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .
- [4] t_t is the same as t_{THL} and t_{TLH} .
- [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$$
 where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

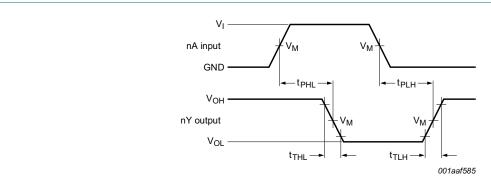
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

11. Waveforms



Measurement points are given in Table 10.

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 6. Propagation delay data input (nA) to output (nY) and output transition time

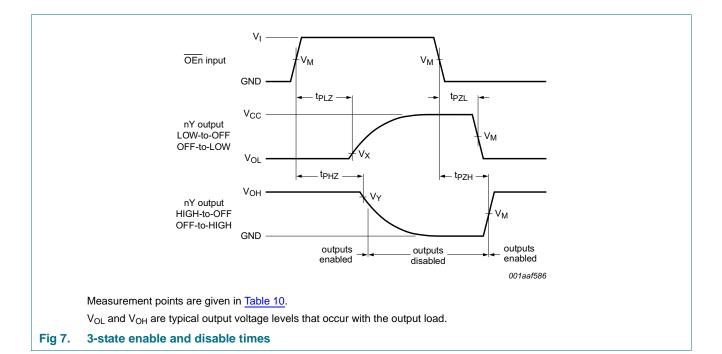
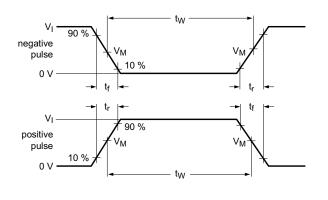
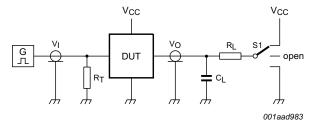


Table 10. Measurement points

Туре	Input	Output		
	V _M	V _M	V _X	V _Y
74HC366	0.5V _{CC}	0.5V _{CC}	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$
74HCT366	1.3 V	1.3 V	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$





Test data is given in Table 11.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator

C_L = Load capacitance including jig and probe capacitance

R_L = Load resistance

S1 = Test selection switch

Fig 8. Test circuit for measuring switching times

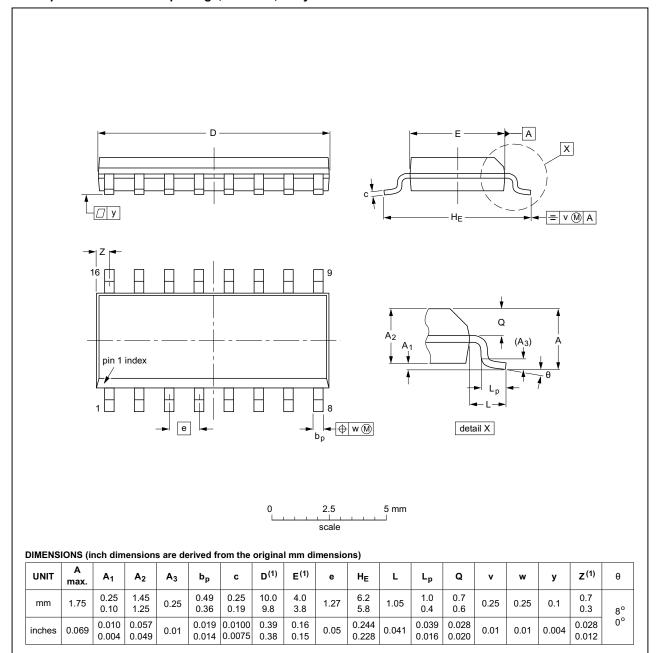
Table 11. Test data

Туре	Input		Load	pad S1 position			
	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
74HC366	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}
74HCT366	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

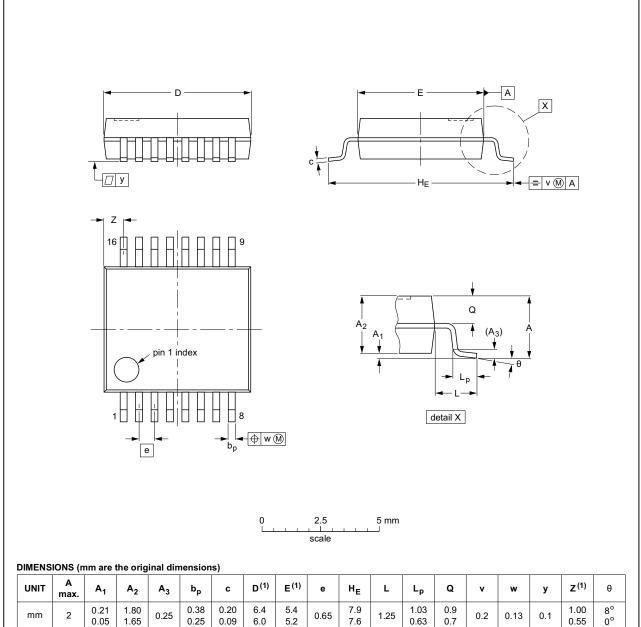
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SOT109-1	076E07	MS-012			99-12-27 03-02-19

Fig 9. Package outline SOT109-1 (SO16)

74HC_HCT366

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

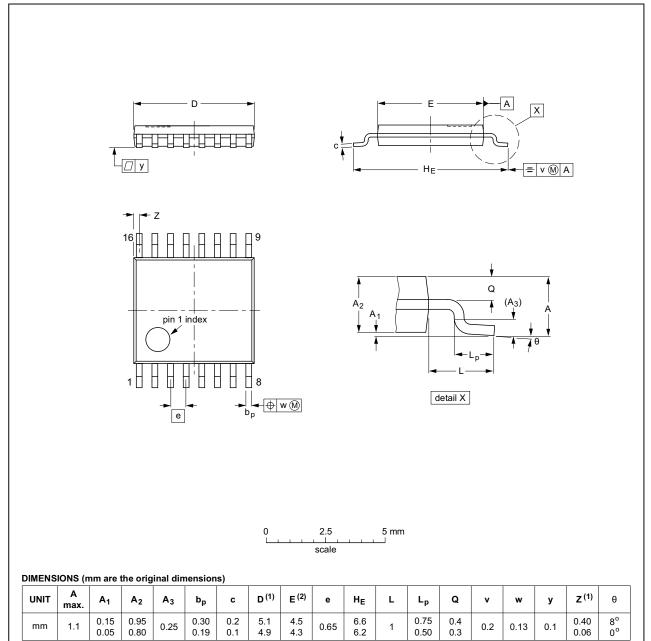
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	1920E DATE
SOT338-1		MO-150			99-12-27 03-02-19

Fig 10. Package outline SOT338-1 (SSOP16)

74HC_HCT366

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT403-1		MO-153			99-12-27 03-02-18

Fig 11. Package outline SOT403-1 (TSSOP16)

74HC_HCT366

13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT366 v.5	20160202	Product data sheet	-	74HC_HCT366 v.4			
Modifications:	Type numbers	s 74HC366N and 74HCT366N	(SOT38-4) removed	d.			
74HC_HCT366 v.4	20120904	Product data sheet	-	74HC_HCT366 v.3			
Modifications:	Legal pages i	updated.					
74HC_HCT366 v.3	20061121	Product data sheet	-	74HC_HCT366_CNV v.2			
74HC_HCT366_CNV v.2	19901201	Product specification	-	-			

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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74HC HCT366

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